

In the Specification:

Please amend paragraph [0043] on page 16 as follows:

—Figure 9 shows a cross-sectional view of an embodiment of the present invention, wherein a thin insulating layer (such as layer 212 in Figure 4) is not used, or wherein the thin insulating layer 212 is completely removed before depositing a gate dielectric material 308/318. Similar reference numbers are designated for the various elements as were used in Figures 3 through 7. To avoid repetition, each reference number shown in the diagram is not described in detail herein. Rather, similar materials x02, x04, x05, etc... are preferably used for the material layers shown as were described for Figures 3 through 7, where x=2 in Figures 3 through 7 and x=3 in Figure 9. As an example, the preferred and alternative materials listed for gate dielectric material 208 in the description for Figures 3 through 7 are preferably also used for gate dielectric material 308 in Figure 9.Figure 3.—